SWITCHMODE™ Power Rectifiers

This series uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

Features

- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Shipped 50 units per plastic tube
- Pb-Free Packages are Available*

Mechanical Characteristics:

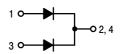
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

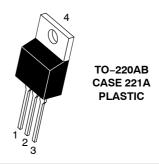


ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 20 AMPERES 80-100 VOLTS





MARKING DIAGRAM



A = Assembly Location

Y = Year

WW = Work Week

B20x0 = Device Code

x = 8, 9 or 10

G = Pb-Free Device

AKA = Polarity Designator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (Per Diode Leg)

		MBR			
Rating	Symbol	2080CT	2090CT	20100CT	Uni
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	80	90	100	٧
Average Rectified Forward Current (Rated V _R) T _C = 133°C	I _{F(AV)}	10		Α	
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) T _C = 133°C	I _{FRM}	20		Α	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	150			Α
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	0.5		Α	
Operating Junction Temperature (Note 1)	TJ	- 65 to +175		°C	
Storage Temperature	T _{stg}	- 65 to +175		°C	
Voltage Rate of Change (Rated V _R)	dv/dt		10,000		V/µs
HERMAL CHARACTERISTICS					
Maximum Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$		2.0 60		°C/W
ELECTRICAL CHARACTERISTICS (Per Diode Leg)	•	•			
Maximum Instantaneous Forward Voltage (Note 2) $ \begin{aligned} &(i_F=10 \text{ Amps, } T_C=125^{\circ}\text{C}) \\ &(i_F=10 \text{ Amps, } T_C=25^{\circ}\text{C}) \\ &(i_F=20 \text{ Amps, } T_C=125^{\circ}\text{C}) \\ &(i_F=20 \text{ Amps, } T_C=25^{\circ}\text{C}) \end{aligned} $	VF	0.75 0.85 0.85 0.95		V	
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^{\circ}C$) (Rated dc Voltage, $T_C = 25^{\circ}C$)	İR	6.0 0.1		mA	

^{1.} The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$. 2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

ORDERING INFORMATION

Device	Package	Shipping [†]	
MBR2080CT	TO-220		
MBR2080CTG	TO-220 (Pb-Free)	50 Units / Rail	
MBR2090CT	TO-220		
MBR2090CTG	TO-220 (Pb-Free)	50 Units / Rail	
MBR20100CT	TO-220		
MBR20100CTG	TO-220 (Pb-Free)	50 Units / Rail	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

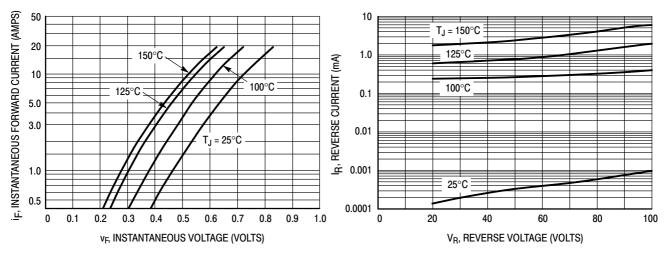


Figure 1. Typical Forward Voltage Per Diode

Figure 2. Typical Reverse Current Per Diode

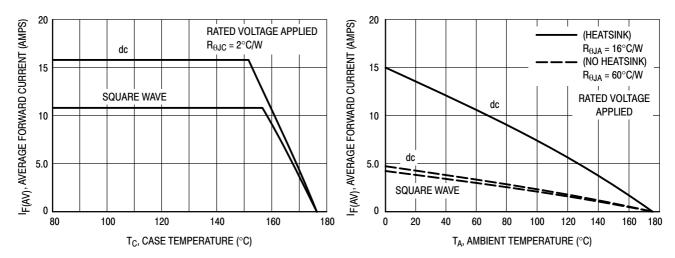


Figure 3. Typical Current Derating, Case, Per Leg

Figure 4. Typical Current Derating, Ambient, Per Leg

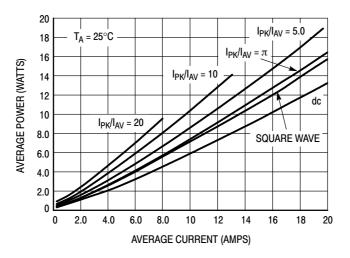
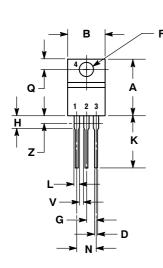
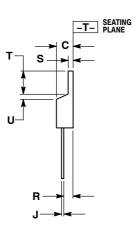


Figure 5. Average Power Dissipation and Average Current

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AF





NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH
- DIMENSION Z DEFINES A ZONE WHERE ALL **BODY AND LEAD IRREGULARITIES ARE**

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

PIN 1.

- ANODE CATHODE 2.
- ANODE
- CATHODE

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